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SAM™ Data Sheet SAM-1064-30-2ps-x, λ = 1064 nm

Laser wavelength	$\lambda = 1064 \text{ nm}$	
High reflection band	λ = 990 1090 nm	
Absorbance	A ₀ = 30 %	
Modulation depth	∆R = 17 %	
Non-saturable loss	A _{ns} = 13 %	
Saturation fluence	Φ_{sat} = 25 µJ/cm ²	
Relaxation time constant	τ ~ 2 ps	
Damage threshold	Φ = 1.5 mJ/cm ²	
Chip area	4.0 mm x 4.0 mm; other dimensions on request	
Chip thickness	450 μm	
Protection	the SAM is protected with a dielectric front layer	
Mounting option x denotes the type of mounting as follows: $\mathbf{x} = 0$ unmounted		
x = 12.7 a	alued on a gold plated Cu-cylinder with 12.7 mm \emptyset	

x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm $arnothing$
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm $arnothing$
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.4 mm $arnothing$
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

